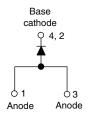


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High Performance Schottky Rectifier, 3.0 A





Single die

8 mJ

D-PAK	(TO-252AA)
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Diode variation

EAS

D-PAK (TO-252AA)
3.0 A
20 V, 30 V, 40 V
0.49 V
20 mA at 125 °C
150 °C

FEATURES

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability



- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-MBRD320-M3, VS-MBRD330-M3, VS-MBRD340-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	3.0	А				
V _{RRM}		20 to 40	V				
I _{FSM}	t _p = 5 μs sine	490	Α				
V _F	3 A _{pk} , T _J = 125 °C	0.49	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS					
PARAMETER SYMBOL VS-MBRD320-M3 VS-MBRD340-M3 UNITS					UNITS
Maximum DC reverse voltage	V_{R}	20	30	40	V
Maximum working peak reverse voltage	V_{RWM}	20	30	40	V

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 133 °C, rectangular waveform		3.0			
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	А		
		10 ms sine or 6 ms rect. pulse	V _{RRM} applied	75			
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 16 mH		8.0	mJ		
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T_J maximum $V_A = 1.5 \times V_R$ typical		1.0	Α		

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ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS			MAX.	UNITS
		3 A	T _{.1} = 25 °C	0.48	0.6	
Maximum forward voltage drop	V _{FM} ⁽¹⁾	6 A	1]=25 0	0.58	0.7	V
See fig. 1	VFM (1)	3 A	T. ₁ = 125 °C	0.41	0.49	
		6 A	1J = 125 C	0.55	0.625	
Maximum reverse leakage current	I _{RM} ⁽¹⁾	T _J = 25 °C	V _B = Rated V _B	0.02	0.2	mA
See fig. 2	IRM ("/	T _J = 125 °C	VR = nateu VR	10.7	20	I IIIA
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		189	-	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	-	nH
Maximum voltage rate of change	dV/dt	Rated V _R		=	10 000	V/µs

Note

 $^{^{(1)}\,}$ Pulse width $<300~\mu s,$ duty cycle <2~%

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction temperature range	T _J ⁽¹⁾		-40 to +150	20
Maximum storage temperature range	T _{Stg}		-40 to +175	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	6.0	°C AM
Maximum thermal resistance, junction to ambient	R _{thJA}		80	°C/W
Annyayimata waight			0.3	g
Approximate weight			0.01	OZ.
			MBRI	D320
Marking device		Case style D-PAK (similar to TO-252AA)	MBRD330	
			MBRI	D340

Note

(1)
$$\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$$
 thermal runaway condition for a diode on its own heatsink



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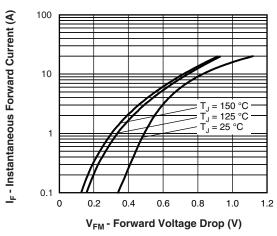


Fig. 1 - Maximum Forward Voltage Drop Characteristics

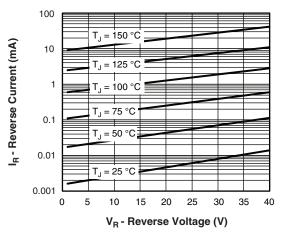


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

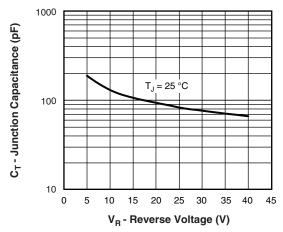


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

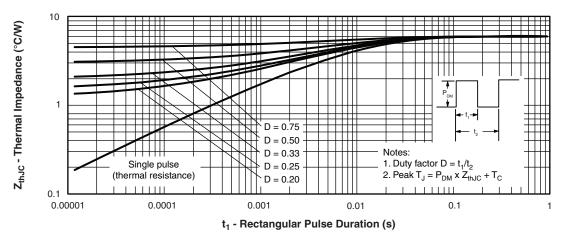


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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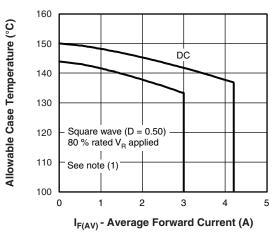


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

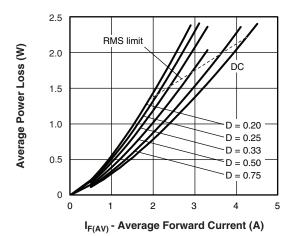


Fig. 6 - Forward Power Loss Characteristics

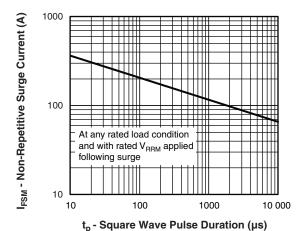


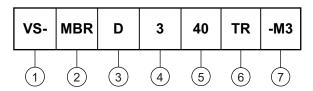
Fig. 7 - Maximum Non-Repetitive Surge Current

Note

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

Schottky MBR series

D = TO-252AA (D-PAK)

Current rating (3 = 3 A)

20 = 20 VVoltage ratings -30 = 30 V40 = 40 V

• None = tube

• TR = tape and reel

• TRL = tape and reel (left oriented)

• TRR = tape and reel (right oriented)

7 Environmental digit:

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-MBRD320-M3	75	3000	Antistatic plastic tube				
VS-MBRD320TR-M3	2000	2000	13" diameter reel				
VS-MBRD320TRL-M3	3000	3000	13" diameter reel				
VS-MBRD320TRR-M3	3000	3000	13" diameter reel				
VS-MBRD330-M3	75	3000	Antistatic plastic tube				
VS-MBRD330TR-M3	2000	2000	13" diameter reel				
VS-MBRD330TRL-M3	3000	3000	13" diameter reel				
VS-MBRD330TRR-M3	3000	3000	13" diameter reel				
VS-MBRD340-M3	75	3000	Antistatic plastic tube				
VS-MBRD340TR-M3	2000	2000	13" diameter reel				
VS-MBRD340TRL-M3	3000	3000	13" diameter reel				
VS-MBRD340TRR-M3	3000	3000	13" diameter reel				

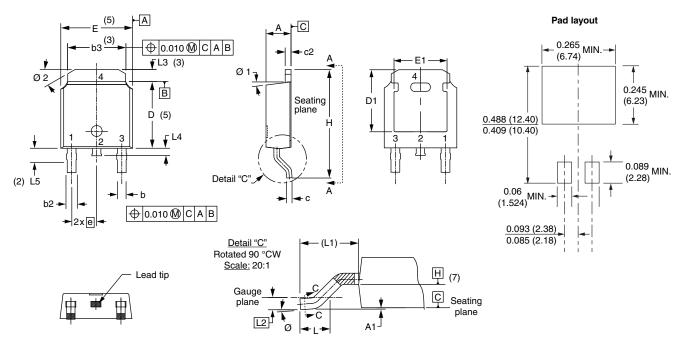
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95627			
Part marking information	www.vishay.com/doc?95176			
Packaging information	www.vishay.com/doc?95033			



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D-PAK (TO-252AA) "M"

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	S INCHES		NOTES
STIVIDOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	2.18	2.39	0.086	0.094	
A1	-	0.13	-	0.005	
b	0.64	0.89	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	3
С	0.46	0.61	0.018	0.024	
c2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	5
D1	5.21	-	0.205	-	3
Е	6.35	6.73	0.250	0.265	5
E1	4.32	-	0.170	-	3

SYMBOL	MILLIN	IETERS	INCHES		NOTES	
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
е	2.29	BSC	0.090	BSC		
Н	9.40	10.41	0.370	0.410		
L	1.40	1.78	0.055	0.070		
L1	2.74	2.74 BSC		0.108 REF.		
L2	0.51	0.51 BSC		0.020 BSC		
L3	0.89	1.27	0.035	0.050	3	
L4	-	1.02	-	0.040		
L5	1.14	1.52	0.045	0.060	2	
Ø	0°	10°	0°	10°		
Ø1	0°	15°	0°	15°		
Ø2	25°	35°	25°	35°		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension uncontrolled in L5
- (3) Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- (4) Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- (5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (6) Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- (8) Outline conforms to JEDEC® outline TO-252AA

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